

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MBR600150CT thru MBR600200CTR

Silicon Power Schottky Diode

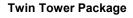
 $V_{RRM} = 150 V - 200 V$

 $I_{F(AV)} = 600 A$

Features

- High Surge Capability
- \bullet Types from 150 V to 200 V V_{RRM}
- Not ESD Sensitive

LUG LUG Teminal Anode 1 Anode 2 Teminal Cathode 1 Cathode 2 Baseplate Common Cathode R=Common Anode







Maximum ratings, at T_i = 25 °C, unless otherwise specified ("R" devices have leads reversed)

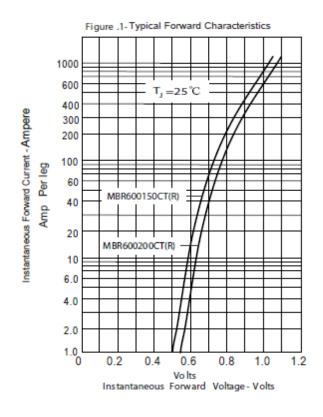
Parameter	Symbol	Conditions	MBR600150CT (R)		MBR600200CT (F	R) Unit
Repetitive peak reverse voltage	V_{RRM}		150		200	V
RMS reverse voltage	V_{RMS}		106		141	V
DC blocking voltage	V_{DC}		150		200	V
Operating temperature	Tj		-55 to 150		-55 to 150	°C
Storage temperature	T _{stg}		-55 to 150	4	-55 to 150	°C

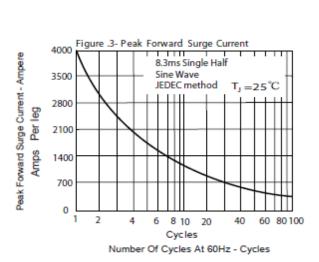
Electrical characteristics, at Tj = 25 °C, unless otherwise specified

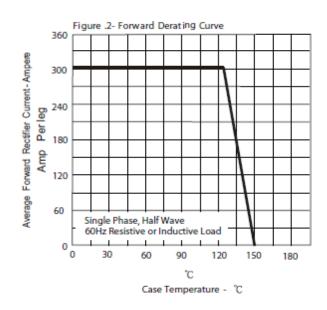
Parameter	Symbol	Conditions	MBR600150CT (R)	MBR600200CT (R)	Unit
Average forward current (per pkg)	I _{F(AV)}	T _C = 125 °C	600	600	А
Peak forward surge current (per leg)	I _{FSM}	t_p = 8.3 ms, half sine	4000	4000	А
Maximum forward voltage (per leg)	V_{F}	I _{FM} = 300 A, T _j = 25 °C	0.88	0.92	V
Reverse current at rated		T _j = 25 °C	3	3	
DC blocking voltage (per	I_R	T _j = 100 °C	10	10	mA
leg)		T _j = 150 °C	50	50	
Thermal characteristic	s				
Thermal resistance, junction-case (per leg)	R _{oJC}		0.28	0.28	°C/W

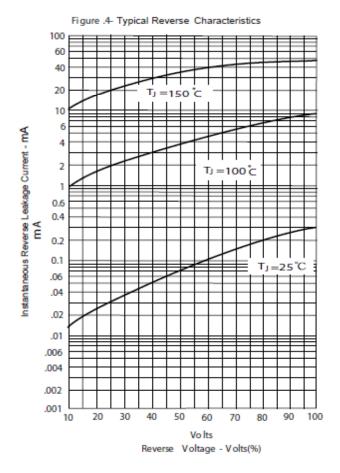


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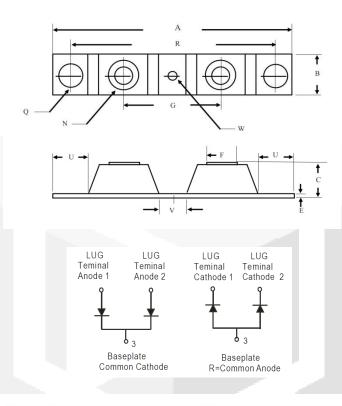




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Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



DIM	Inc	ehes	Millimeters		
	Min	Max	Min	Max	
A		3.630		92.40	
В	0.700	0.800	17.78	20.32	
С		0.650		16.51	
Е	0.130	0.141	3.30	3.60	
F	0.482	0.490	12.25	12.45	
G	1.368	BSC	34.75	BSC	
N		1/4-20 UNC	FULL		
Q	0.275	0.290	6.99	7.37	
R	3.150	BSC	80.01	BSC	
U	0.600		15.24		
V	0.312	0.370	7.92	9.40	
W	0.180	0.195	4.57	4.95	